

Phenomenological Description of Microwave Characteristics of Low- T_c Superconductor by Three-Fluid Model

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SUMMARY It is shown that a three-fluid model, which was successfully introduced to explain microwave characteristics of high- T_c superconductors phenomenologically, is suit also to explain those of low- T_c superconductors. In this model, the two contributions of a residual normal electron, in addition to a super and a normal electron in the two-fluid model, and of the temperature (T) dependence of momentum relaxation time τ for the two normal electrons are taken into account. Measured results of the T dependence of surface resistance R_s for a Nb film with critical temperature $T_c=9.2$ K agree very well with an R_s curve calculated using the present model, where a residual surface resistance at $T=0$ K, R_{s0} , and the T dependence of τ were determined using the surface reactance at 0 K $X_{s0}=37.6$ m Ω calculated using the BCS theory to fit a calculated R_s curve with the measured values as a function of T . Furthermore, microwave characteristics predicted from the BCS theory cannot be explained phenomenologically using the conventional two-fluid model. This difficulty can be solved by using an improved two-fluid model, called the two-fluid (τ) model, where the T dependence of τ is taken into account. Finally the frequency dependence of R_s calculated for the Nb film is $f^{1.9}$ for the BCS theory and $f^{2.0}$ for the three-fluid (τ) model on the assumption of the frequency independence of τ .

key words: low- T_c superconductors, microwave, surface impedance, conductivity

1. Introduction

For microwave applications of superconductors, it is important to investigate microwave behavior of their surface impedance $Z_s=R_s+jX_s$, where R_s is the surface resistance and X_s is the surface reactance, and their complex conductivity $\sigma=\sigma_1-j\sigma_2$. Conventional BCS theory [1], [2] and two-fluid model [3] have been commonly used to explain the microwave characteristics of metallic low- T_c superconductors, although residual loss due to acoustic loss is suggested to play an important role in real materials below the temperature $T=0.33T_c$ [4], where T_c is the critical temperature. In addition we cannot explain the peak of σ_1 appearing just below T_c , which is predicted from calculations based on the BCS theory, using the two-fluid model.

On the other hand, a three-fluid model proposed

by the authors [5]-[6], which is designated as "three-fluid (τ) model," was successfully introduced to explain microwave characteristics of high- T_c superconductors phenomenologically. In this model, two contributions are taken into account: one is of a residual normal electron in addition to a super and a normal electron in the conventional two-fluid model, and the other is that of the T dependence of momentum relaxation time τ for both these normal electrons.

In this paper, the validity of the three-fluid (τ) model is discussed to explain microwave characteristics of low- T_c superconductors. Furthermore, an improved two-fluid model, which is designated as "two-fluid (τ) model" and corresponds to the case of $R_{s0}=0$ in the three-fluid (τ) model or to a two-fluid model with τ dependent on temperature, is introduced to explain a peak of σ_1 appearing just below T_c , which is predicted from the BCS theory but cannot be explained by the conventional two-fluid model. The behaviors of the three-fluid (τ), two-fluid (τ), and two-fluid models and BCS theory are compared with measured results of the T dependence of R_s for a Nb film with $T_c=9.2$ K [10]. Finally, the frequency dependence of R_s for the Nb film is discussed from results evaluated using these models.

2. Calculation of Z_s and σ

2.1 The Three-Fluid (τ) Model

In the two-fluid model [3], as is well known, it is assumed that total electron density n , which is given as the sum of superelectron density n_s and normal electron density n_n , that is, $n=n_s+n_n$, is independent of T and the T dependences of n_s and n_n are given by

$$n_s=n\left[1-\left(\frac{T}{T_c}\right)^4\right] \quad n_n=n\left[1-\left(\frac{T}{T_c}\right)^4\right]. \quad (1)$$

In the three-fluid (τ) model [8], residual normal electron density n_{res} , which is assumed to be independent of T , is added to n of the two-fluid model; that is,

$$n_t=n_s+n_n+n_{res}=n+n_{res}. \quad (2)$$

where n_t is the total electron density which is also independent of T . In addition, the T dependence of

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momentum relaxation time τ for n_n and n_{res} are taken into account. For high- T_c superconductors, the following equation, which was derived by Imai and Kobayashi [8] on the basis of measured results presented by Romero, et al. [11], was used:

$$\tau = \tau_c \left(\frac{T}{T_c} \right)^\alpha + \tau_0 \left\{ 1 - \left(\frac{T}{T_c} \right)^\alpha \right\} \quad (T \leq T_c), \quad (3)$$

where τ_c is τ at T_c K, $\tau_0 (> \tau_c)$ is τ at 0 K, and α is a constant. Equation (3) is assumed to be valid also for low- T_c superconductors. The process of calculating Z_s and σ by the present model is described elsewhere [8] and reviewed briefly below. First, R_{sn} and R_{s0} , which are R_s values at T_c and 0 K, respectively, are determined from the result of the T dependence of R_s measured at f_0 for a superconductor with T_c K. Second, X_{s0} , which is the X_s value at 0 K, is taken to be equal to one calculated using the BCS theory, as discussed later. Third, fitting parameters $A = \tau_c/\tau_0$ and α in Eq. (3) are determined so as to fit a R_s curve, calculated using the model, with the measured R_s values. Fourth, the values of n_{res} , n , τ_0 , and τ are calculated according to Ref. [8]. Finally complex conductivity $\sigma = \sigma_1 - j\sigma_2$ is given by

$$\sigma_1 = \frac{(n_n + n_{res}) e^2 \tau}{m(\omega^2 \tau^2 + 1)} \quad (4)$$

$$\sigma_2 = \frac{n_s e^2}{m\omega} + \frac{(n_n + n_{res}) e^2 \tau^2 \omega}{m(\omega^2 \tau^2 + 1)}, \quad (5)$$

where $e = -1.6022 \times 10^{-19}$ C is the electron charge, $m = 9.1096 \times 10^{-31}$ kg is the mass of an electron, and ω is the angular frequency. Then the relationship between Z_s and σ is given by

$$Z_s = \sqrt{\frac{j\omega\mu_0}{\sigma}}, \quad (6)$$

where $\mu_0 = 4\pi \times 10^{-7}$ H/m is the permeability.

2.2 The Two-Fluid Model and the Two-Fluid (τ) Model

The two-fluid [3] and two-fluid (τ) models correspond to the case of $n_{res} = 0$ for the three-fluid model described above; thus Eqs. (4) and (5) yield

$$\sigma_1 = \frac{n_n e^2 \tau}{m(\omega^2 \tau^2 + 1)} \quad (7)$$

$$\sigma_2 = \frac{n_s e^2}{m\omega} + \frac{n_n e^2 \tau^2 \omega}{m(\omega^2 \tau^2 + 1)}, \quad (8)$$

where τ is independent of T for the two-fluid model and is given by Eq. (3) also for the two-fluid (τ) model. Then R_s and X_s are calculated from Eqs. (6), (7) and (8).

2.3 The BCS Theory

For the BCS theory σ_1 and σ_2 are given by [1], [2]

$$\frac{\sigma_1}{\sigma_n} = \frac{2}{\hbar\omega} \int_{\Delta}^{\infty} [f(E) - f(E + \hbar\omega)] g(E) dE + \frac{1}{\hbar\omega} \int_{\Delta - \hbar\omega}^{-\Delta} [1 - 2f(E + \hbar\omega)] g(E) dE \quad (9)$$

$$\frac{\sigma_2}{\sigma_n} = \frac{1}{\hbar\omega} \int_{\Delta - \hbar\omega}^{\Delta} [1 - 2f(E + \hbar\omega)] \times \frac{E^2 + \Delta^2 + \hbar\omega E}{\sqrt{\Delta^2 - E^2} \sqrt{(E + \hbar\omega)^2 - \Delta^2}} dE. \quad (10)$$

where

$$f(E) = \frac{1}{1 + \exp(E/K_B T)} \quad (11)$$

$$g(E) = \frac{E^2 + \Delta^2 + \hbar\omega E}{\sqrt{E^2 - \Delta^2} \sqrt{(E + \hbar\omega)^2 - \Delta^2}} \quad (12)$$

$$\sigma_n = \frac{\omega\mu_0}{R_{sn}^2}. \quad (13)$$

In the above, $\hbar = h/2\pi = 1.0546 \times 10^{-34}$ Js is the Planck's constant, $K_B = 1.3806 \times 10^{-23}$ J/K is the Boltzmann's constant, and $f(E)$ is the Fermi function. The energy gap Δ is given by

$$\frac{1}{N(0)V} = \int_0^{\hbar\omega_c} \frac{\tanh \frac{1}{2} \beta \sqrt{\xi^2 + \Delta^2}}{\sqrt{\xi^2 + \Delta^2}} d\xi, \quad (14)$$

where $N(0)$ is the density of states of one spin in energy at the Fermi surface, V is the attractive phonon interaction dominate of a constant average [1] and β is given by

$$\beta = \frac{1}{K_B T}. \quad (15)$$

Since Δ becomes 0 for $T = T_c$, Eq. (14) is expressed as

$$\frac{1}{N(0)V} = \int_0^{\beta_c \hbar\omega_c / 2} \frac{\tanh x}{x} dx, \quad (16)$$

where β_c and ω_c are values of β and ω at T_c K. In actual numerical calculation, first the value of $1/N(0)V$ independent of T is calculated from Eq. (16), second the Δ values are calculated from Eqs. (14) and (15) as a function of T , third σ_1 and σ_2 are calculated from Eqs. (9) to (13), and finally R_s and X_s are calculated from Eq. (6).

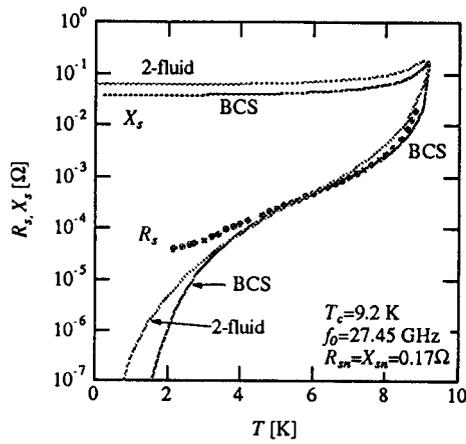
3. Measured and Calculated Results for a Nb Film

3.1 R_s -Curve Fitting of Two-Fluid Model into BCS Theory

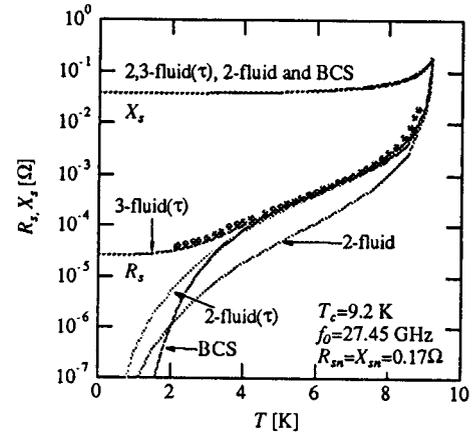
First, the T dependence of Z_s according to the BCS

theory was calculated from Eqs. (6) and (9) to (16) using $R_{sn}=X_{sn}=0.17\ \Omega$ so as to fit the R_s values measured at 27.45 GHz for a Nb film with $T_c=9.2\ \text{K}$ [10]. In a similar manner, that in the two-fluid model

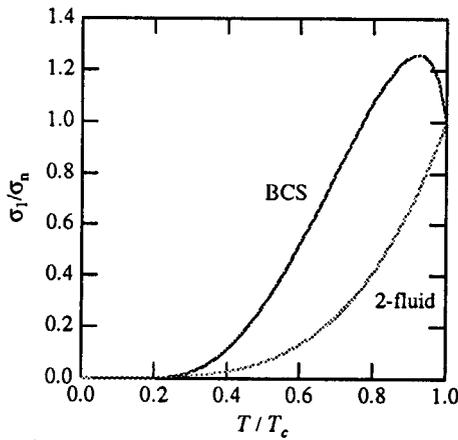
was calculated from Eqs. (6), (7) and (8) using $\tau=3.79\times 10^{-13}\ \text{sec}$ and $n=3.51\times 10^{26}\ \text{m}^{-3}$, which are independent of T . These results are shown in Fig. 1(a).



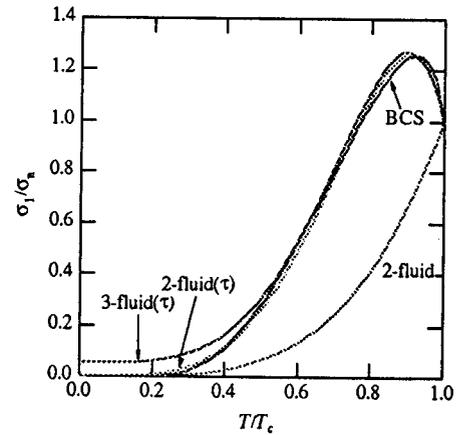
(a) $R_s, X_s - T$



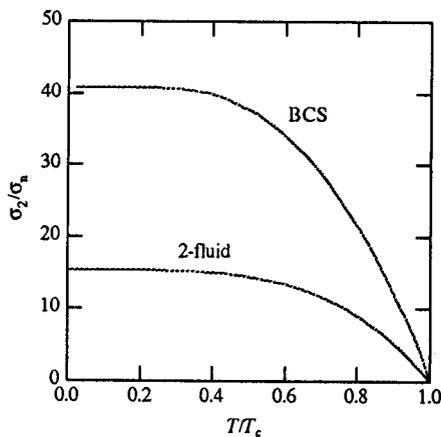
(a) $R_s, X_s - T$



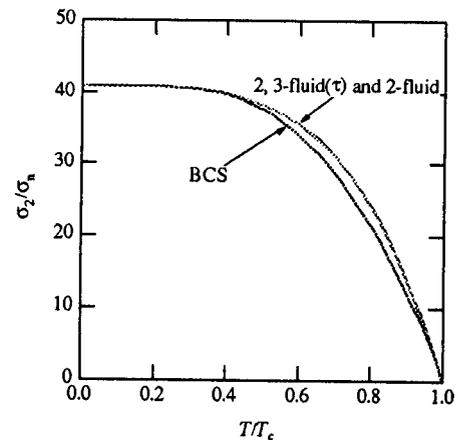
(b) $\sigma_1/\sigma_n - T/T_c$



(b) $\sigma_1/\sigma_n - T/T_c$



(c) $\sigma_2/\sigma_n - T/T_c$



(c) $\sigma_2/\sigma_n - T/T_c$

Fig. 1 Measured results of R_s for the Nb film, calculated results using the BCS theory and the two-fluid model in which the R_s curve is fitted with the measured R_s values.

Fig. 2 Measured results of R_s for the Nb film and Z_s and σ calculated using the four models when $X_{s0}=37.6\ \text{m}\Omega$ calculated from the BCS theory was used for other models.

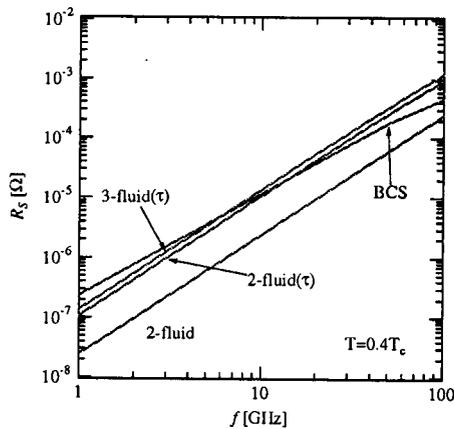
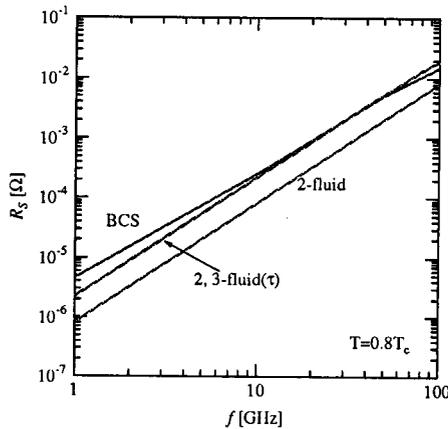
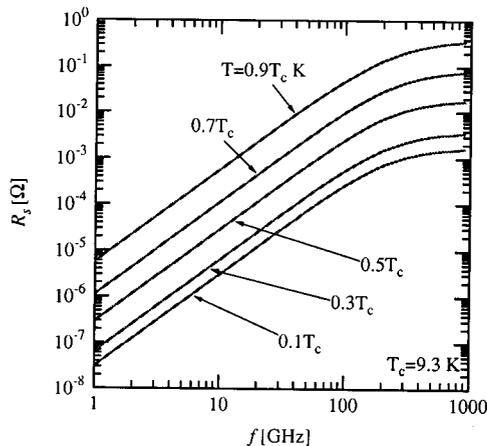

 (a) $R_s - f$ at $T=0.4T_c$ K

 (b) $R_s - f$ at $T=0.8T_c$ K

Fig. 4 Calculated results of the frequency dependence of R_s using the four models.

Fig. 5 Calculated results of the frequency dependence of R_s using the three-fluid (τ) model.

(τ) model in the frequency range from 1 to 1000 GHz are shown in Fig. 5. The f^2 dependences of R_s are constant independent of T below 70 GHz, and the influence of the term $\omega\tau$ in Eqs. (4) and (5) appears

for the frequency dependences of R_s over 70 GHz.

5. Conclusion

Conclusions are summarized as follows.

(1) The three-fluid (τ) model is useful for phenomenological description of the T dependence of the measured R_s values of a Nb film at temperatures below T_c .

(2) Microwave characteristics predicted from the BCS theory cannot be explained phenomenologically by the conventional two-fluid model, where the T dependence of τ is not taken into account. This difficulty can be solved by using the two-fluid (τ) model, where the T dependence of τ is taken into account.

(3) The frequency dependence of R_s calculated for a Nb film with $T_c=9.2$ K using the BCS theory is $f^{1.9}$ below 40 GHz. On the other hand, the results calculated by the three-fluid (τ) model on the assumption of the frequency independence of τ is $f^{2.0}$ below 70 GHz.

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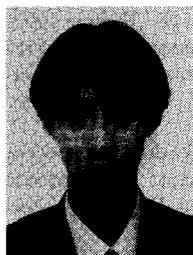
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